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Attorney Docket No.: 02307Z-132800US Client Reference No.: 2003-145-1 i fw

Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

TOWNSEND and TOWNSEND and CREW LLP

Mark T. Davis

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Julin Wan, Amiya K. Mukherjee, and Matthew J. Gasch

Application No.: 10/773,758

Filed: February 6, 2004

For: NANOCOMPOSITES OF SILICON NITRIDE, SILICON CARBIDE, AND

BORON NITRIDE

Examiner: Not Yet Assigned

Art Unit: 1755

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR §1.97 and

§1.98

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The references cited on attached form PTO/SB/08B are being called to the attention of the Examiner. Copies of the non-U.S. references are enclosed. In accordance with the USPTO waiver of the requirement under 37 CFR 1.98 (a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. patent application publication for all U.S. patent applications filed after June 30, 2003, applicant has not submitted copies of the U.S. references.

As provided for by 37 CFR 1.97(g) and (h), no inference should be made that the information and references cited are prior art merely because they are in this statement and no representation is being made that a search has been conducted or that this statement encompasses all the possible relevant information.

Julin Wan, Amiya K. Mukherjee, and Matthew J.

Gasch

Application No.: 10/773,758

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Applicant believes that <u>no fee is required</u> for submission of this statement.

However, if a fee is required, the Commissioner is authorized to deduct such fee from the undersigned's Deposit Account No. 20-1430. Please deduct any additional fees from, or credit any overpayment to, the above-noted Deposit Account.

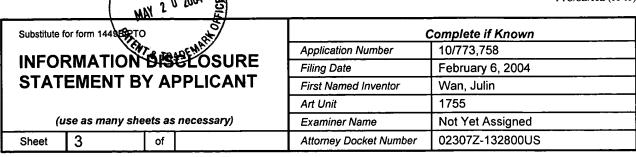
Respectfully submitted,

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U.S. PATENT DOCUMENTS+					
		Document Number			
Examiner Initials*	Cite No.1	Number Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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			NOI	N PATENT LIT	ERATURE DOG	CUMENTS		
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Signature	Considered	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Substitute for form 1449B/PTO TRADEMARKS

INFORMATION DISCLOSURE
STATEMENT BY APPLICANT

Complete if Known

Application Number 10/773,758

Filing Date February 6, 2004

First Named Inventor Wan, Julin

Art Unit 1755

Examiner Name Not Yet Assigned

Attorney Docket Number 02307Z-132800US

(use as many sheets as necessary)

Sheet 4 of

		FOREIGN PA	TENT DOCUME	ENTS		
Examiner Initials*		Foreign Patent Document		Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines,	
	Cite No. ¹	Country Code ³ Number ⁴ Kind Code ⁸ (if known)	Publication Date MM-DD-YYYY		Where Relevant Passages or Relevant Figures Appear	⊤°
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	AQ	WANG, Zhi-Chang et al.; "Novel Silicon-Boron-Ca Ceram. Soc., 2001, Vol. 84, No. 10, pp. 2179-218		als Thermally Stable up to	2200 °C"; <u>J.Am.</u>	
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